





MMBT3904

NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBT3906)
- Ideal for Medium Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound, (Note 3). UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)





B E

Device Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | 60 | V |
| Collector-Emitter Voltage | V_{CEO} | 40 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current - Continuous (Note 1) | Ic | 200 | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|----------------|-------------|------|
| Power Dissipation (Note 1) | P _D | 300 | mW |
| Thermal Resistance, Junction to Ambient (Note 1) | $R_{	hetaJA}$ | 417 | °C/W |
| Operating and Storage and Temperature Range | T.i. Tstg | -55 to +150 | °C |

Notes:

- 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.
- Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition | | | |
|--|----------------------|-----------------------------|-----------------|--------------------|---|--|--|--|
| OFF CHARACTERISTICS | | | | | | | | |
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | 60 | | V | $I_C = 10\mu A, I_E = 0$ | | | |
| Collector-Emitter Breakdown Voltage (Note 4) | $V_{(BR)CEO}$ | 40 | | V | $I_C = 1.0 \text{mA}, I_B = 0$ | | | |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | 6.0 | | V | $I_E = 10 \mu A, I_C = 0$ | | | |
| Collector Cutoff Current | I _{CEX} | _ | 50 | nA | $V_{CE} = 30V, V_{EB(OFF)} = 3.0V$ | | | |
| Base Cutoff Current | I_{BL} | _ | 50 | nA | $V_{CE} = 30V$, $V_{EB(OFF)} = 3.0V$ | | | |
| ON CHARACTERISTICS (Note 4) | | | | | | | | |
| DC Current Gain | h _{FE} | 40 70 100 60 30 | 300 | _ | $\begin{split} & _{C} = 100 \mu \text{A}, \ V_{CE} = 1.0 \text{V} \\ & _{C} = 1.0 \text{mA}, \ V_{CE} = 1.0 \text{V} \\ & _{C} = 10 \text{mA}, \ V_{CE} = 1.0 \text{V} \\ & _{C} = 50 \text{mA}, \ V_{CE} = 1.0 \text{V} \\ & _{C} = 100 \text{mA}, \ V_{CE} = 1.0 \text{V} \end{split}$ | | | |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | | 0.20 0.30 | V | $I_C = 10$ mA, $I_B = 1.0$ mA $I_C = 50$ mA, $I_B = 5.0$ mA | | | |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | 0.65 | 0.85 0.95 | V | $I_C = 10mA, I_B = 1.0mA$ $I_C = 50mA, I_B = 5.0mA$ | | | |
| SMALL SIGNAL CHARACTERISTICS | | | | - | | | | |
| Output Capacitance | Cobo | _ | 4.0 | pF | $V_{CB} = 5.0V$, $f = 1.0MHz$, $I_E = 0$ | | | |
| Input Capacitance | C _{ibo} | _ | 8.0 | pF | $V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$ | | | |
| Input Impedance | h _{ie} | 1.0 | 10 | kΩ | | | | |
| Voltage Feedback Ratio | h _{re} | 0.5 | 8.0 | x 10 ⁻⁴ | $V_{CE} = 10V, I_{C} = 1.0mA,$ | | | |
| Small Signal Current Gain | h _{fe} | 100 | 400 | _ | f = 1.0kHz | | | |
| Output Admittance | h _{oe} | 1.0 | 40 | μS | | | | |
| Current Gain-Bandwidth Product | f _T | 300 | | MHz | $V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz | | | |
| Noise Figure | | _ | 5.0 | dB | $V_{CE} = 5.0V$, $I_{C} = 100\mu A$, $R_{S} = 1.0k\Omega$, $f = 1.0kHz$ | | | |
| SWITCHING CHARACTERISTICS | | | | | | | | |
| Delay Time | t _d | _ | 35 | ns | $V_{CC} = 3.0V, I_{C} = 10mA,$ | | | |
| Rise Time | t _r | _ | 35 | ns | $V_{BE(off)} = -0.5V, I_{B1} = 1.0mA$ | | | |
| Storage Time | ts | _ | 200 | ns | $V_{CC} = 3.0V, I_{C} = 10mA,$ | | | |
| Fall Time | t _f | | 50 | ns | $I_{B1} = I_{B2} = 1.0 \text{mA}$ | | | |

Notes: 4. Short duration pulse test used to minimize self-heating effect.

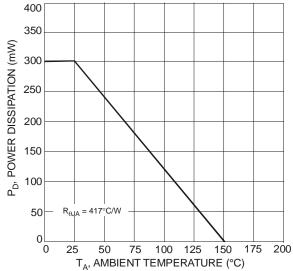
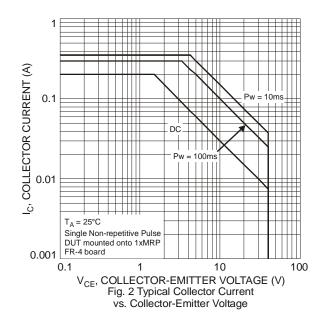


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 1)





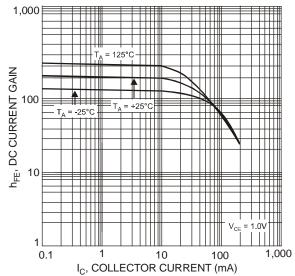
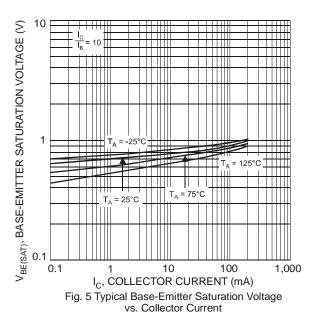
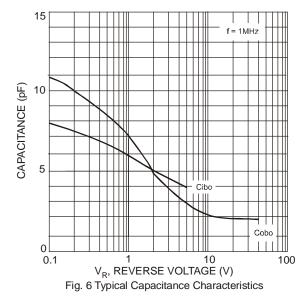


Fig. 3 Typical DC Current Gain vs. Collector Current



O.01 O.1 1 1 10 100 1,000 I.c, COLLECTOR CURRENT (mA)

Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

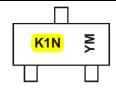


Ordering Information (Note 5)

| Part Number | Case | Packaging | | |
|--------------|--------|------------------|--|--|
| MMBT3904-7-F | SOT-23 | 3000/Tape & Reel | | |

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



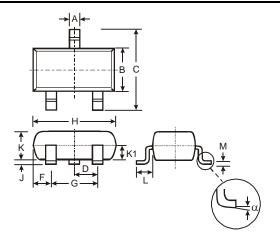
K1N = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 | 2013 | 2014 | 2015 |
|-------|------|------|------|------|------|------|------|------|------|------|-------|------|------|------|------|------|------|------|
| Code | J | K | L | М | N | Р | R | S | Т | U | V | W | Χ | Υ | Z | Α | В | С |
| Month | Jan | 1 | Feb | Mai | r | Apr | May | / | Jun | Jul | ı [. | Aug | Sep | | Oct | Nov | , | Dec |
| Code | 1 | | 2 | 3 | | 4 | 5 | | 6 | 7 | | 8 | 9 | | 0 | N | | D |

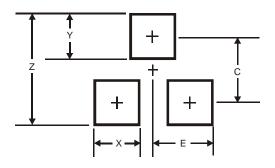


Package Outline Dimensions



| SOT-23 | | | | | | | |
|--------|----------------------|------|-------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | |
| C | 2.30 | 2.50 | 2.40 | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | |
| H | 2.80 | 3.00 | 2.90 | | | | |
| 7 | 0.013 | 0.10 | 0.05 | | | | |
| K | 0.903 | 1.10 | 1.00 | | | | |
| K1 | - | 1 | 0.400 | | | | |
| L | 0.45 | 0.61 | 0.55 | | | | |
| М | 0.085 | 0.18 | 0.11 | | | | |
| α | 0° | 8° | - | | | | |
| All | All Dimensions in mm | | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Υ | 0.9 |
| С | 2.0 |
| E | 1.35 |

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